

UTC UNISONIC TECHNOLOGIES CO., LTD

MCR08

Preliminary

SENSITIVE GATE SILICON **CONTROLLED RECTIFIER**

DESCRIPTION

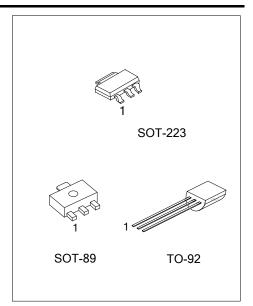
The UTC MCR08 is a 0.8A SCR, it uses UTC's advanced technology to provide customers with sensitive gate trigger current, etc.

The UTC MCR08 is suitable for line powered consumer applications such as relay and lamp drivers, small motor controls, gate drivers for larger thyristors, and sensing and detection circuits.

FEATURES

- * Blocking voltage to 600V
- * Sensitive gate trigger current
- * Glass passivated surface for reliability and uniformity

ORDERING INFORMATION



Ordering Number		Daakaga	Pin assignment			Deaking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MCR08L-2-AA3-R	MCR08G-2-AA3-R	SOT-223	Κ	А	G	Tape Reel	
MCR08L-2-AB3-R	MCR08G-2-AB3-R	SOT-89	G	А	K	Tape Reel	
MCR08L-2-T92-B	MCR08G-2-T92-B	TO-92	Κ	G	Α	Tape Box	
MCR08L-2-T92-K	MCR08G-2-T92-K	TO-92	Κ	G	Α	Bulk	
MCR08L-6-AA3-R	MCR08G-6-AA3-R	SOT-223	Κ	А	G	Tape Reel	
MCR08L-6-AB3-R	MCR08G-6-AB3-R	SOT-89	G	А	K	Tape Reel	
MCR08L-6-T92-B	MCR08G-6-T92-B	TO-92	Κ	G	Α	Tape Box	
MCR08L-6-T92-K	MCR08G-6-T92-K	TO-92	K	G	Α	Bulk	
Note: Pin assignment: G: Gate	K: Cathode A: Anode						

ote: Pin assignment: G: Gate K: Cathode A: Anode

MCR08G-2-AA3-R		
	(1) Packing Type	(1) B: Tape Box, K: Bulk, R: Tape Reel
	(2) Package Type	(2) AA3: SOT-223, AB3: SOT-89, T92: TO-92
	(3) Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

MARKING

Package	MCR100-2	MCR100-6
SOT-223	MCR08 -2 □□□□ → G: Halogen Free → Date Code	MCR08 -6 -6 → Date Code
SOT-89	Date Code M2 → L: Lead Free G: Halogen Free	Date Code MG L: Lead Free G: Halogen Free
TO-92	UTC MCR08 L: Lead Free -2 G: Halogen Free Date Code	UTC MCR08 L: Lead Free -6 C: Halogen Free -6 Date Code



■ ABSOLUTE MAXIMUM RATINGS (T_=25°C unless otherwise noted)

PARAMETER	SYMBOL	RATINGS	UNIT	
Peak Repetitive Off-State Voltage (Note 1)	eak Repetitive Off-State Voltage (Note 1) MCR08-2		200	V
(Sine Wave, R _{GK} =1kΩ T _J =25~110°C)	MCR08-6	V _{RRM}	600	V
On-State Current RMS (All Conduction Angle	s, T _C =80°C)	I _{T(RMS)}	0.8	А
Peak Non-repetitive Surge Current (1/2 Cycle Sine Wave, 60Hz, T _C =25°C)		I _{TSM}	8.0	А
Circuit Fusing Considerations (t =8.3ms)		l ² t	0.4	A ² s
Forward Peak Gate Power (T _C =80°C, t =1.0µs)		P _{GM}	0.1	W
Average Gate Power (T _C =80°C, t=8.3ms)		P _{G(AV)}	0.01	W
Operating Junction Temperature		TJ	-40 ~ +110	°C
Storage Temperature	T _{STG}	-40 ~ +150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL DATA

PA	RAMETER	SYMBOL	MAX	UNIT
	SOT-223		180	°C/W
Junction to Ambient	SOT-89	θ _{JA}	400	°C/W
	TO-92		200	°C/W

ELECTRICAL CHARACTERISTICS (Tc=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
DFF CHARACTERISTICS							
Peak Repetitive Forward or Reverse		V _{AK} =Rated V _{DRM} or	TJ=25°C			10	μA
Blocking Current (Note 3)	I _{DRM} , I _{RRM}	V_{RRM} , R_{GK} =1k Ω T _J =110°C				200	μA
ON CHARACTERISTICS	_						
Peak Forward On-State Voltage (Note 2)	V _{TM} I _T =1.0A Peak				1.7	V	
Gate Trigger Current (Continuous dc) (Note 4)	I _{GT}	V_{AK} =12Vdc, R _L =100 Ω				200	μA
Holding Current (Note 3)	Ι _Η	V _{AK} =12Vdc, Initiating Current=20mA				5.0	mA
Gate Trigger Voltage (Continuous dc) (Note 4)	V _{GT}	V_{AK} =12Vdc, R _L =100 Ω				0.8	V
Turn-On Time	t _{gt}	V _{AK} =12Vdc, I _{TM} =5Adc, I _{GT} =5mA			1.25		μs
DYNAMIC CHARACTERISTICS						_	
Critical Rate-of-Rise of Off State Voltage	dv/dt	V_{pk} =Rated V_{DRM} , T_{C} =110°C, R _{GK} =1k Ω , Exponential Method 10				V/µs	

Notes: 1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant source such that the voltage ratings of the devices are exceeded.

2. Pulse Test: Pulse width≤300µs, Duty cycle≤2%.

3. R_{GK} =1000 Ω is included in measurement.

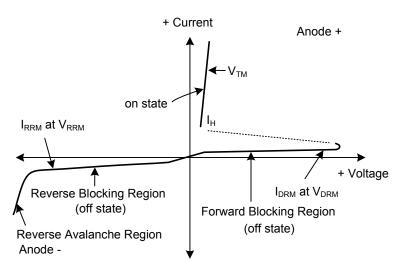
4. R_{GK} is not included in measurement.



MCR08

■ VOLTAGE CURRENT CHARACTERISTIC OF SCR

PARAMETER	SYMBOL
Peak Repetitive Off Stat Forward Voltage	V _{DRM}
Peak Forward Blocking Current	I _{DRM}
Peak Repetitive Off State Reverse Voltage	V _{RRM}
Peak Reverse Blocking Current	I _{RRM}
Peak On State Voltage	V _{TM}
Holding Current	I _H



Voltage Current Characteristic of SCR

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